# 74HC594; 74HCT594

# 8-bit shift register with output register

Rev. 6 — 22 October 2021

Product data sheet

### 1. General description

The 74HC594; 74HCT594 is an 8-bit serial-in/serial or parallel-out shift register with a storage register. Separate clock and reset inputs are provided on both shift and storage registers. The device features a serial input (DS) and a serial output (Q7S) to enable cascading. Data is shifted on the LOW-to-HIGH transitions of the SHCP input, and the data in the shift register is transferred to the storage register on a LOW-to-HIGH transition of the STCP input. If both clocks are connected together, the shift register will always be one clock pulse ahead of the storage register. A LOW level on one of the two register reset pins ( $\overline{\text{SHR}}$  and  $\overline{\text{STR}}$ ) will clear the corresponding register. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of  $V_{CC}$ .

#### 2. Features and benefits

- · Synchronous serial input and output
- 8-bit parallel output
- · Shift and storage registers have independent direct clear and clocks
- · Independent clocks for shift and storage registers
- 100 MHz (typical)
- Wide supply voltage range from 2.0 V to 6.0 V
- CMOS low power dissipation
- · High noise immunity
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- Input levels:
  - For 74HC594: CMOS level
  - For 74HCT594: TTL level
- Complies with JEDEC standards
  - JESD8C (2.7 V to 3.6 V)
  - JESD7A (2.0 V to 6.0 V)
- ESD protection:
  - HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0  $\Omega$ )
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

# 3. Applications

- · Serial-to parallel data conversion
- · Remote control holding register

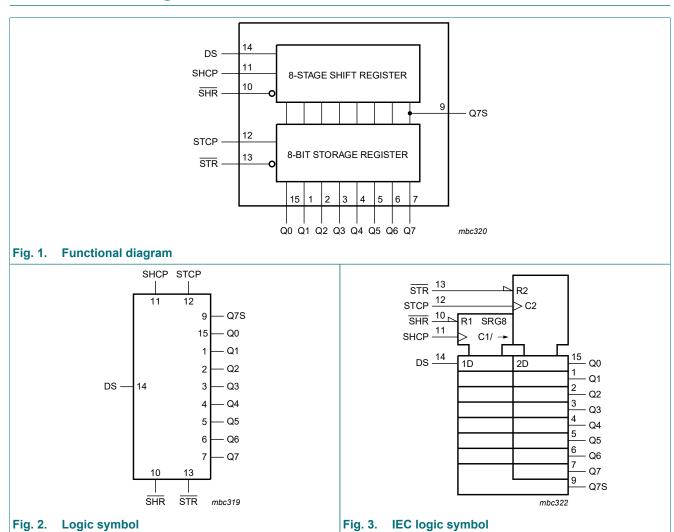


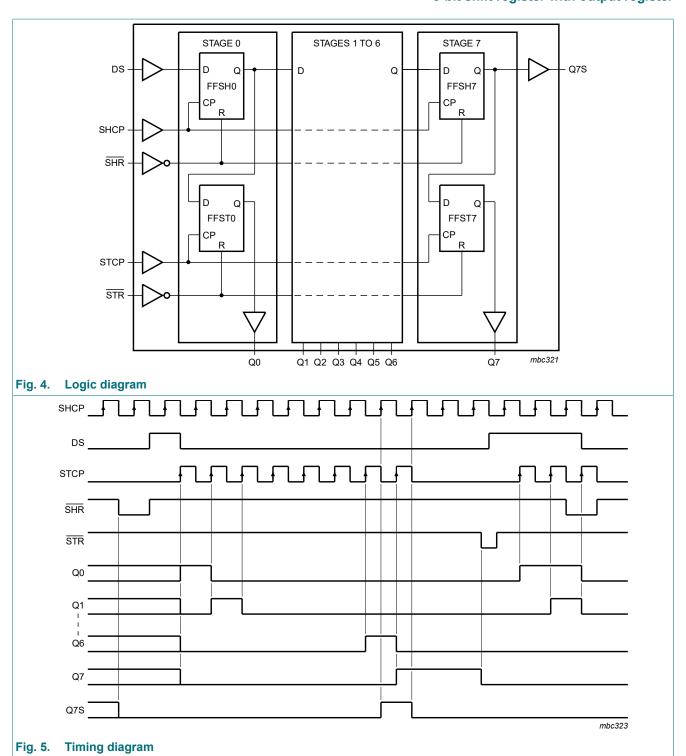
# 4. Ordering information

**Table 1. Ordering information** 

Type number	Package								
	Temperature range	Name	Description	Version					
74HC594D	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads;	SOT109-1					
74HCT594D			body width 3.9 mm						
74HC594DB	-40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads;	SOT338-1					
74HCT594DB			body width 5.3 mm						
74HC594PW	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads;	SOT403-1					
74HCT594PW			body width 4.4 mm						

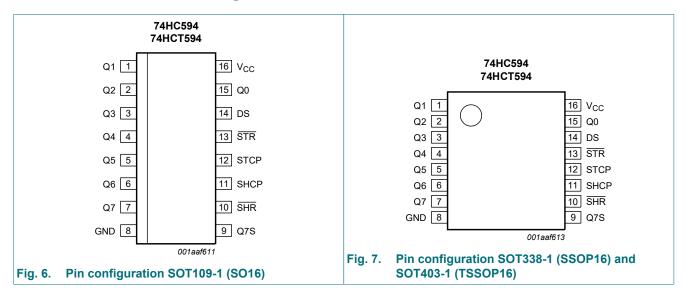
# 5. Functional diagram





# 6. Pinning information

#### 6.1. Pinning



### 6.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
Q0, Q1, Q2, Q3, Q4, Q5, Q6, Q7	15, 1, 2, 3, 4, 5, 6, 7	parallel data output
GND	8	ground (0 V)
Q7S	9	serial data output
SHR	10	shift register reset (active LOW)
SHCP	11	shift register clock input
STCP	12	storage register clock input
STR	13	storage register reset (active LOW)
DS	14	serial data input
V <sub>CC</sub>	16	supply voltage

# 7. Functional description

#### Table 3. Function table

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level; \ \uparrow = LOW - to - HIGH \ transition; \ X = don't \ care.$ 

Function	Input				
	SHR	STR	SHCP	STCP	DS
Clear shift register	L	Х	Х	Х	Х
Clear storage register	Х	L	X	X	Х
Load DS into shift register stage 0, advance previous stage data to the next stage	Н	Х	1	X	H or L
Transfer shift register data to storage register and outputs Qn	Х	Н	X	1	Х
Shift register one count pulse ahead of storage register	Н	Н	1	1	X

# 8. Limiting values

#### **Table 4. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CC</sub>	supply voltage			-0.5	+7.0	V
I <sub>IK</sub>	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	[1]	-	±20	mA
I <sub>OK</sub>	output clamping current	$V_{O}$ < -0.5 V or $V_{O}$ > $V_{CC}$ + 0.5 V	[1]	-	±20	mA
Io	output current	$V_{O} = -0.5 \text{ V to } V_{CC} + 0.5 \text{ V}$				
		Serial data output Q7S		-	±25	mA
		Parallel data output Qn		-	±35	mA
I <sub>CC</sub>	supply current	Serial data output Q7S		-	50	mA
		Parallel data output Qn		-	70	mA
I <sub>GND</sub>	ground current	Serial data output Q7S		-	-50	mA
		Parallel data output Qn		-	-70	mA
T <sub>stg</sub>	storage temperature			-65	+150	°C
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = -40 °C to +125 °C	[2]	-	500	mW

<sup>[1]</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

For SOT338-1 (SSOP16) package: Ptot derates linearly with 8.5 mW/K above 91 °C.

For SOT403-1 (TSSOP16) package: Ptot derates linearly with 8.5 mW/K above 91 °C.

# 9. Recommended operating conditions

#### Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions		74HC594			74HCT594			
			Min	Тур	Max	Min	Тур	Max		
V <sub>CC</sub>	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V	
VI	input voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V	
Vo	output voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V	
T <sub>amb</sub>	ambient temperature		-40	-	+125	-40	-	+125	°C	
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 2.0 V	-	-	625	-	-	-	ns/V	
		V <sub>CC</sub> = 4.5 V	-	1.67	139	-	1.67	139	ns/V	
		V <sub>CC</sub> = 6.0 V	-	-	83	-	-	-	ns/V	

<sup>[2]</sup> For SOT109-1 (SO16) package: Ptot derates linearly with 12.4 mW/K above 110 °C.

# 10. Static characteristics

#### Table 6. Static characteristics type 74HC594

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = 2	25 °C	,	'	'	-	
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 2.0 V	1.5	1.2	-	V
		V <sub>CC</sub> = 4.5 V	3.15	2.4	-	V
		V <sub>CC</sub> = 6.0 V	4.2	3.2	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	0.8	0.5	V
		V <sub>CC</sub> = 4.5 V	-	2.1	1.35	V
		V <sub>CC</sub> = 6.0 V	-	2.8	1.8	V
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		Q7S; $I_O = -4.0 \text{ mA}$ ; $V_{CC} = 4.5 \text{ V}$	3.98	4.32	-	V
		Q7S; $I_0 = -5.2 \text{ mA}$ ; $V_{CC} = 6.0 \text{ V}$	5.48	5.81	-	V
		Qn; I <sub>O</sub> = -6.0 mA; V <sub>CC</sub> = 4.5 V	3.98	4.32	-	V
		Qn; I <sub>O</sub> = -7.8 mA; V <sub>CC</sub> = 6.0 V	5.48	5.81	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		Q7S; I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 4.5 V	-	0.15	0.26	V
		Q7S; I <sub>O</sub> = 5.2 mA; V <sub>CC</sub> = 6.0 V	-	0.16	0.26	V
		Qn; I <sub>O</sub> = 6.0 mA; V <sub>CC</sub> = 4.5 V	-	0.15	0.26	V
		Qn; I <sub>O</sub> = 7.8 mA; V <sub>CC</sub> = 6.0 V	-	0.16	0.26	V
l <sub>l</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	μA
I <sub>CC</sub>	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 6.0 \text{ V}$	-	-	8.0	μΑ
Ci	input capacitance		-	3.5	-	pF
T <sub>amb</sub> = -	40 °C to +85 °C					
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 2.0 V	1.5	-	-	V
		V <sub>CC</sub> = 4.5 V	3.15	-	-	V
		V <sub>CC</sub> = 6.0 V	4.2	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	-	0.5	V
		V <sub>CC</sub> = 4.5 V	-	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	-	1.8	V
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		Q7S; $I_O = -4.0 \text{ mA}$ ; $V_{CC} = 4.5 \text{ V}$	3.84	-	-	V
		Q7S; $I_O = -5.2 \text{ mA}$ ; $V_{CC} = 6.0 \text{ V}$	5.34	-	-	V
		Qn; I <sub>O</sub> = -6.0 mA; V <sub>CC</sub> = 4.5 V	3.84	-	-	V
		Qn; I <sub>O</sub> = -7.8 mA; V <sub>CC</sub> = 6.0 V	5.34	-	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		Q7S; $I_O = 4.0 \text{ mA}$ ; $V_{CC} = 4.5 \text{ V}$	-	-	0.33	V
		Q7S; $I_O = 5.2 \text{ mA}$ ; $V_{CC} = 6.0 \text{ V}$	-	-	0.33	V
		Qn; I <sub>O</sub> = 6.0 mA; V <sub>CC</sub> = 4.5 V	-	-	0.33	V
		Qn; I <sub>O</sub> = 7.8 mA; V <sub>CC</sub> = 6.0 V	-	-	0.33	V
I <sub>I</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±1.0	μA
I <sub>CC</sub>	supply current	$V_1 = V_{CC}$ or GND; $I_0 = 0$ A; $V_{CC} = 6.0$ V	-	-	80	μA

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = -4	40 °C to +125 °C					
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 2.0 V	1.5	-	-	V
		V <sub>CC</sub> = 4.5 V	3.15	-	-	V
		V <sub>CC</sub> = 6.0 V	4.2	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	-	0.5	V
		V <sub>CC</sub> = 4.5 V	-	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	-	1.8	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		Q7S; I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 4.5 V	3.7	-	-	V
		Q7S; $I_0 = -5.2 \text{ mA}$ ; $V_{CC} = 6.0 \text{ V}$	5.2	-	-	V
		Qn; I <sub>O</sub> = -6.0 mA; V <sub>CC</sub> = 4.5 V	3.7	-	-	V
		Qn; I <sub>O</sub> = -7.8 mA; V <sub>CC</sub> = 6.0 V	5.2	-	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		Q7S; I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 4.5 V	-	-	0.4	V
		Q7S; $I_0 = 5.2 \text{ mA}$ ; $V_{CC} = 6.0 \text{ V}$	-	-	0.4	V
		Qn; I <sub>O</sub> = 6.0 mA; V <sub>CC</sub> = 4.5 V	-	-	0.4	V
V <sub>OL</sub>		Qn; I <sub>O</sub> = 7.8 mA; V <sub>CC</sub> = 6.0 V	-	-	0.4	V
l <sub>l</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±1.0	μA
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0$ V	-	-	160	μΑ

#### Table 7. Static characteristics type 74HCT594

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = 2	5 °C					
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	1.6	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	1.2	0.8	V
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		Q7S; I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 4.5 V	3.98	4.32	-	V
		Qn; I <sub>O</sub> = -6.0 mA; V <sub>CC</sub> = 4.5 V	3.98	4.32	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		Q7S; I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 4.5 V	-	0.15	0.26	V
		Qn; I <sub>O</sub> = 6.0 mA; V <sub>CC</sub> = 4.5 V	-	0.16	0.26	V
II	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±0.1	μΑ
I <sub>CC</sub>	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 5.5$ V	-	-	8.0	μA
ΔI <sub>CC</sub>	additional supply current	per input pin; $V_I = V_{CC} - 2.1 \text{ V}$ and other inputs at $V_{CC}$ or GND; $I_O = 0 \text{ A}$ ; $V_{CC} = 4.5 \text{ V}$ to $5.5 \text{ V}$				
		pins SHR, SHCP, STCP, STR	-	150	540	μΑ
		pin DS	-	25	90	μΑ
C <sub>i</sub>	input capacitance		-	3.5	-	pF

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = -	40 °C to +85 °C				1	
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	0.8	V
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		Q7S; $I_O = -4.0 \text{ mA}$ ; $V_{CC} = 4.5 \text{ V}$	3.84	-	-	V
		Qn; I <sub>O</sub> = -6.0 mA; V <sub>CC</sub> = 4.5 V	3.84	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		Q7S; I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 4.5 V	-	-	0.33	V
		Qn; I <sub>O</sub> = 6.0 mA; V <sub>CC</sub> = 4.5 V	-	-	0.33	V
I <sub>I</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±1.0	μA
I <sub>CC</sub>	supply current $V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V		-	-	80	μA
ΔI <sub>CC</sub>	additional supply current	per input pin; $V_I = V_{CC}$ - 2.1 V and other inputs at $V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 4.5$ V to 5.5 V				
		pins SHR, SHCP, STCP, STR	-	-	675	μΑ
		pin DS	-	-	112.5	μA
T <sub>amb</sub> = -	40 °C to +125 °C				1	
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	0.8	V
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		Q7S; I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 4.5 V	3.7	-	-	V
		Qn; I <sub>O</sub> = -6.0 mA; V <sub>CC</sub> = 4.5 V	3.7	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		Q7S; I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 4.5 V	-	-	0.4	V
		Qn; I <sub>O</sub> = 6.0 mA; V <sub>CC</sub> = 4.5 V	-	-	0.4	V
I <sub>I</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±1.0	μA
I <sub>CC</sub>	supply current	current $V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V		-	160	μA
ΔI <sub>CC</sub>	additional supply current	per input pin; $V_I = V_{CC}$ - 2.1 V and other inputs at $V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 4.5$ V to 5.5 V				
		pins SHR, SHCP, STCP, STR	-	-	735	μA
		pin DS	-	-	122.5	μA

# 11. Dynamic characteristics

Table 8. Dynamic characteristics type 74HC594

GND = 0 V;  $t_r = t_f = 6$  ns;  $C_L = 50$  pF; For test circuit see Fig. 14.

Symbol	Parameter	Conditions		25 °C		-40 °C to	o +85 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
t <sub>pd</sub>	propagation	SHCP to Q7S; see Fig. 8 [1]								
	delay	V <sub>CC</sub> = 2.0 V	-	44	150	-	185	-	225	ns
		V <sub>CC</sub> = 4.5 V	-	16	30	-	37	-	45	ns
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	13	-	-	-	-	-	ns
		V <sub>CC</sub> = 6.0 V	-	14	26	-	31	-	38	ns
		STCP to Qn; see Fig. 9								
		V <sub>CC</sub> = 2.0 V	-	44	150	-	185	-	225	ns
		V <sub>CC</sub> = 4.5 V	-	16	30	-	37	-	45	ns
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	13	-	-	-	-	-	ns
		V <sub>CC</sub> = 6.0 V	-	14	26	-	31	-	38	ns
t <sub>PHL</sub>	HIGH	SHR to Q7S; see Fig. 12								
	to LOW propagation	V <sub>CC</sub> = 2.0 V	-	39	150	-	185	-	225	ns
	delay	V <sub>CC</sub> = 4.5 V	-	14	30	-	37	-	45	ns
	Juliay	V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	11	-	-	-	-	-	ns
		V <sub>CC</sub> = 6.0 V	-	12	26	-	31	-	38	ns
		STR to Qn; see Fig. 13								
		V <sub>CC</sub> = 2.0 V	-	39	125	-	155	-	185	ns
		V <sub>CC</sub> = 4.5 V	-	14	25	-	31	-	37	ns
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	11	-	-	-	-	-	ns
		V <sub>CC</sub> = 6.0 V	-	12	21	-	26	-	31	ns
t <sub>THL</sub>	HIGH to	Q7S; see Fig. 8								
	LOW output transition	V <sub>CC</sub> = 2.0 V	-	19	75	-	95	-	110	ns
	time	V <sub>CC</sub> = 4.5 V	-	7	15	-	19	-	22	ns
		V <sub>CC</sub> = 6.0 V	-	6	13	-	16	-	19	ns
		Qn								
		V <sub>CC</sub> = 2.0 V	-	14	60	-	75	-	90	ns
		V <sub>CC</sub> = 4.5 V	-	5	12	-	15	-	18	ns
		V <sub>CC</sub> = 6.0 V	-	4	10	-	13	-	15	ns
t <sub>TLH</sub>	LOW to	Q7S; see Fig. 8								
	HIGH output transition	V <sub>CC</sub> = 2.0 V	-	19	75	-	95	-	110	ns
	time	V <sub>CC</sub> = 4.5 V	-	7	15	-	19	-	22	ns
		V <sub>CC</sub> = 6.0 V	-	6	13	-	16	-	19	ns
		Qn								
		V <sub>CC</sub> = 2.0 V	-	14	60	-	75	-	90	ns
		V <sub>CC</sub> = 4.5 V	-	5	12	-	15	-	18	ns
		V <sub>CC</sub> = 6.0 V	-	4	10	-	13	-	15	ns

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C t	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
t <sub>W</sub>	pulse width	SHCP (HIGH or LOW); see Fig. 8								
		V <sub>CC</sub> = 2.0 V	80	10	-	100	-	120	-	ns
		V <sub>CC</sub> = 4.5 V	16	4	-	20	-	24	-	ns
		V <sub>CC</sub> = 6.0 V	14	3	-	17	-	20	-	ns
		STCP (HIGH or LOW); see Fig. 9								
		V <sub>CC</sub> = 2.0 V	80	10	-	100	-	120	-	ns
		V <sub>CC</sub> = 4.5 V	16	4	-	20	-	24	-	ns
		V <sub>CC</sub> = 6.0 V	14	3	-	17	-	20	-	ns
		SHR and STR (HIGH or LOW); see Fig. 12 and Fig. 13								
		V <sub>CC</sub> = 2.0 V	80	14	-	100	-	120	-	ns
		V <sub>CC</sub> = 4.5 V	16	5	-	20	-	24	-	ns
		V <sub>CC</sub> = 6.0 V	14	4	-	17	-	20	-	ns
t <sub>su</sub>	set-up time	DS to SHCP; see Fig. 10								
		V <sub>CC</sub> = 2.0 V	100	10	-	125	-	150	-	ns
		V <sub>CC</sub> = 4.5 V	20	4	-	25	-	30	-	ns
		V <sub>CC</sub> = 6.0 V	17	3	-	21	-	26	-	ns
		SHR to STCP; see Fig. 11								
		V <sub>CC</sub> = 2.0 V	100	14	-	125	-	150	-	ns
		V <sub>CC</sub> = 4.5 V	20	5	-	25	-	30	-	ns
		V <sub>CC</sub> = 6.0 V	17	4	-	21	-	26	-	ns
		SHCP to STCP; see Fig. 9								
		V <sub>CC</sub> = 2.0 V	100	17	-	125	-	150	-	ns
		V <sub>CC</sub> = 4.5 V	20	6	-	25	-	30	-	ns
		V <sub>CC</sub> = 6.0 V	17	5	-	21	-	26	-	ns
t <sub>h</sub>	hold time	DS to SHCP; see Fig. 10								
		V <sub>CC</sub> = 2.0 V	25	-8	-	30	-	35	-	ns
		V <sub>CC</sub> = 4.5 V	5	-3	-	6	-	7	-	ns
		V <sub>CC</sub> = 6.0 V	4	-2	-	5	-	6	-	ns
t <sub>rec</sub>	rec recovery time	SHR to SHCP and STR to STCP; see Fig. 12 and Fig. 13								
		V <sub>CC</sub> = 2.0 V	50	-14	-	65	-	75	-	ns
		V <sub>CC</sub> = 4.5 V	10	-5	-	13	-	15	-	ns
		V <sub>CC</sub> = 6.0 V	9	-4	-	11	-	13	-	ns

Symbol	Parameter	Conditions	25 °C		-40 °C to	o +85 °C	-40 °C to	+125 °C	Unit	
			Min	Тур	Max	Min	Max	Min	Max	
f <sub>max</sub>	maximum frequency	SHCP or STCP; see Fig. 8 and Fig. 9								
		V <sub>CC</sub> = 2.0 V	6.0	30	-	4.8	-	4.0	-	MHz
		V <sub>CC</sub> = 4.5 V	30	92	-	24	-	20	-	MHz
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	100	-	-	-	-	-	MHz
		V <sub>CC</sub> = 6.0 V	35	109	-	28	-	24	-	MHz
C <sub>PD</sub>	power dissipation capacitance	$V_1 = GND \text{ to } V_{CC}; V_{CC} = 5 \text{ V}; [2]$ $f_i = 1 \text{ MHz}$	-	84	-	-	-	-	-	pF

f<sub>o</sub> = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;  $\sum (C_L \times V_{CC}^2 \times f_0) = \text{sum of outputs.}$ 

Table 9. Dynamic characteristics type 74HCT594

GND = 0 V;  $V_{CC}$  = 4.5 V;  $t_r$  =  $t_f$  = 6 ns;  $C_L$  = 50 pF; For test circuit see Fig. 14.

Symbol	Parameter	Conditions		25 °C		-40 °C to	o +85 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
t <sub>pd</sub>	propagation	SHCP to Q7S; see Fig. 8 [1]	-	18	32	-	40	-	48	ns
	delay	V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	15	-	-	-	-	-	ns
		STCP to Qn; see Fig. 9	-	18	32	-	40	-	48	ns
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	15	-	-	-	-	-	ns
t <sub>PHL</sub>	HIGH	SHR to Q7S; see Fig. 12	-	17	30	-	38	-	45	ns
	to LOW propagation	V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	14	-	-	-	-	-	ns
	delay	STR to Qn; see Fig. 13	-	17	30	-	38	-	45	ns
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	14	-	-	-	-	-	ns
t <sub>THL</sub>	t <sub>THL</sub> HIGH to	Q7S; see <u>Fig. 8</u>								
	LOW output transition	V <sub>CC</sub> = 4.5 V	-	7	15	-	19	-	22	ns
	time	Qn								
		V <sub>CC</sub> = 4.5 V	-	5	12	-	15	-	18	ns
t <sub>TLH</sub>	LOW to	Q7S; see Fig. 8								
	HIGH output transition	V <sub>CC</sub> = 4.5 V	-	7	15	-	19	-	22	ns
	time	Qn								
		V <sub>CC</sub> = 4.5 V	-	5	12	-	15	-	18	ns
t <sub>W</sub>	pulse width	SHCP (HIGH or LOW); see Fig. 8	16	4	-	20	-	24	-	ns
		STCP (HIGH or LOW); see Fig. 9	16	4	-	20	-	24	-	ns
		SHR and STR (HIGH or LOW); see Fig. 12 and Fig. 13	16	6	-	20	-	24	-	ns

Symbol	Parameter	Conditions		25 °C		-40 °C to	o +85 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
t <sub>su</sub> set-up	set-up time	DS to SHCP; see Fig. 10	20	4	-	25	-	30	-	ns
		SHR to STCP; see Fig. 11	20	6	-	25	-	30	-	ns
		SHCP to STCP; see Fig. 9	20	7	-	25	-	30	-	ns
t <sub>h</sub>	hold time	DS to SHCP; see Fig. 10	5	-3	-	6	-	7	-	ns
t <sub>rec</sub>	recovery time	SHR to SHCP and STR to STCP; see Fig. 12 and Fig. 13	10	-5	-	13	-	15	-	ns
f <sub>max</sub>	maximum frequency	SHCP or STCP; see Fig. 8 and Fig. 9	30	92	-	24	-	20	-	MHz
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	100	-	-	-	-	-	MHz
C <sub>PD</sub>	power dissipation capacitance	$V_I = GND \text{ to } V_{CC} - 1.5 \text{ V};$ [2] $V_{CC} = 5 \text{ V}; f_i = 1 \text{ MHz}$	-	89	-	-	-	-	-	pF

 $t_{pd}$  is the same as  $t_{PHL}$  and  $t_{PLH}$ .  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ):

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$  where:

f<sub>i</sub> = input frequency in MHz;

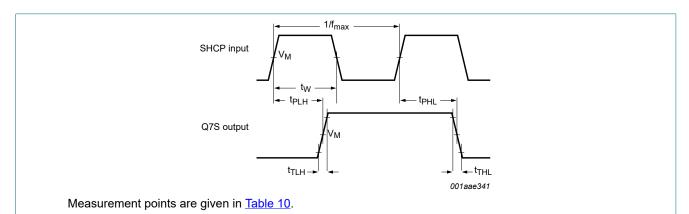
f<sub>o</sub> = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;  $\sum (C_L \times V_{CC}^2 \times f_0) = \text{sum of outputs.}$ 

#### 11.1. Waveforms and test circuit



The shift clock (SHCP) to output (Q7S) propagation delays, the shift clock pulse width, the maximum shift Fig. 8. clock frequency, and output transition times

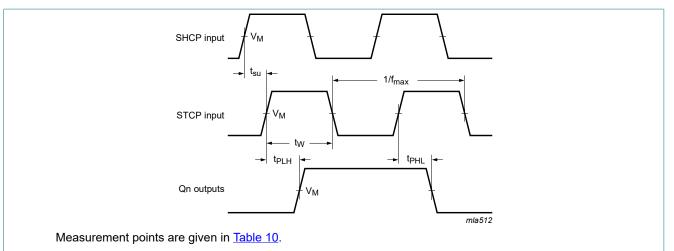
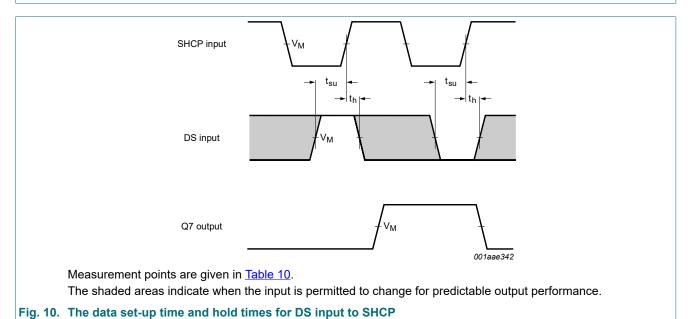


Fig. 9. The storage clock (STCP) to output (Qn), propagation delays, the storage clock pulse width, the maximum storage clock pulse frequency and the shift clock to storage clock set-up time



SHR input

STCP input

Qn outputs

Measurement points are given in Table 10.

Fig. 11. The set-up time shift reset (SHR) to storage clock (STCP)

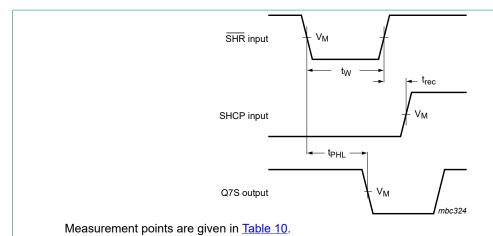
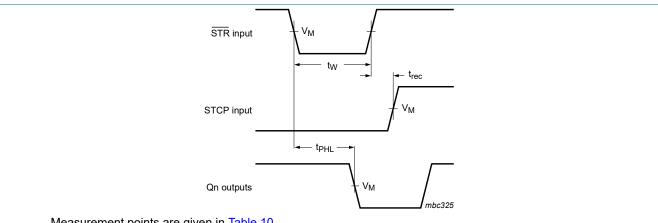


Fig. 12. The shift reset (SHR) pulse width, the shift reset to output (Q7S) propagation delay and the shift reset to shift clock (SHCP) recovery time

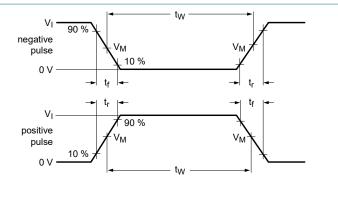


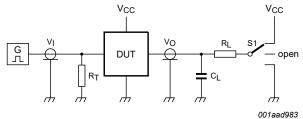
Measurement points are given in Table 10.

Fig. 13. The storage reset (STR) pulse width, the storage reset to output (Qn) propagation delay and the storage reset to storage clock (STCP) recovery time

**Table 10. Measurement points** 

Туре	Input	Output
	V <sub>M</sub>	V <sub>M</sub>
74HC594	0.5 × V <sub>CC</sub>	0.5 × V <sub>CC</sub>
74HCT594	1.3 V	1.3 V





Test data is given in Table 11.

Definitions test circuit:

 $R_T$  = Termination resistance should be equal to output impedance  $Z_o$  of the pulse generator

C<sub>L</sub> = Load capacitance including jig and probe capacitance

R<sub>I</sub> = Load resistance

S1 = Test selection switch

Fig. 14. Test circuit for measuring switching times

Table 11. Test data

Туре	Input		Load		S1 position			
	V <sub>I</sub>	t <sub>r</sub> , t <sub>f</sub>	CL	R <sub>L</sub>	t <sub>PHL</sub> , t <sub>PLH</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>	
74HC594	V <sub>CC</sub>	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V <sub>CC</sub>	
74HCT594	3 V	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V <sub>CC</sub>	

# 12. Package outline

#### SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



UNIT	A max.	<b>A</b> <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	bp	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	10.0 9.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075	0.39 0.38	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.028 0.020	0.01	0.01	0.004	0.028 0.012	0°

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT109-1	076E07	MS-012			<del>99-12-27</del> 03-02-19	

Fig. 15. Package outline SOT109-1 (SO16)

SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1

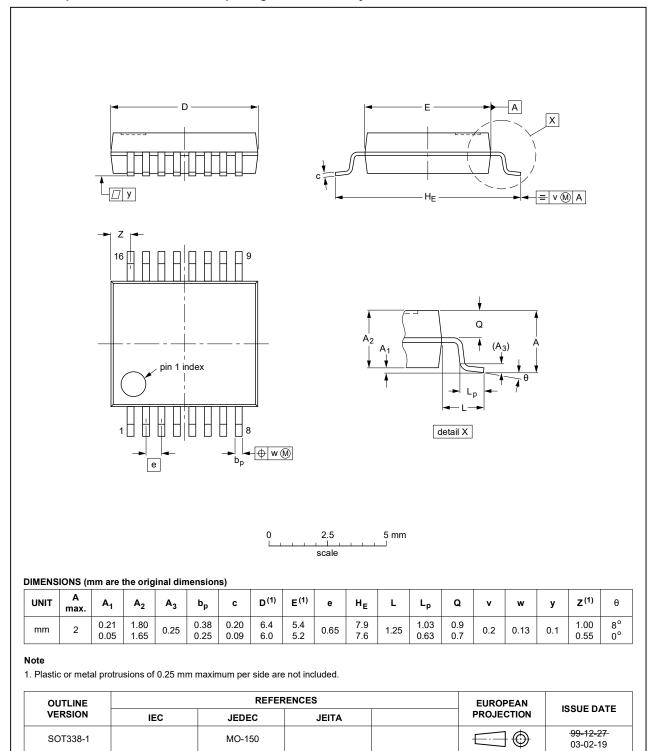
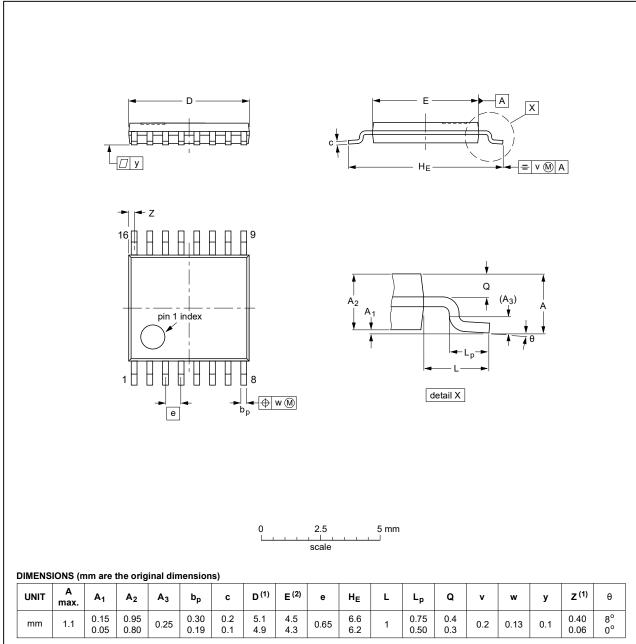


Fig. 16. Package outline SOT338-1 (SSOP16)

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



#### Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUEDATE
SOT403-1		MO-153				<del>99-12-27</del> 03-02-18

Fig. 17. Package outline SOT403-1 (TSSOP16)

# 13. Abbreviations

#### **Table 12. Abbreviations**

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

# 14. Revision history

#### **Table 13. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT594 v.6	20211022	Product data sheet	-	74HC_HCT594 v.5
Modifications:	Type number	er 74HCT594PW (SOT403	-1/TSSOP16) add	led.
74HC_HCT594 v.5	20210812	Product data sheet	-	74HC_HCT594 v.4
Modifications:	guidelines of Legal texts Type number	of this data sheet has beer of Nexperia. have been adapted to the oters 74HC594PW (SOT403- Derating values for P <sub>tot</sub> tota	new company nar -1/TSSOP16) add	ne where appropriate. led.
74HC_HCT594 v.4	20160225	Product data sheet	-	74HC_HCT594 v.3
Modifications:	Type number	ers 74HC594N and 74HCT	594N (SOT38-4)	removed.
74HC_HCT594 v.3	20061220	Product data sheet	-	74HC_HCT594_CNV v.2
Modifications:	guidelines o Legal texts	of this data sheet has beer of NXP Semiconductors. have been adapted to the idering information updated.	new company nar	
74HC_HCT594_CNV v.2	19970908	Product specification	-	74HC_HCT594_CNV v.1

# 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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